

Fixed Attenuator Chip

- ◆ DC to 43.5GHz
- ◆ 8dB
- ◆ 1.2 W



Features

- Adopting advance GaAs technology
- Excellent attenuation accuracy & phase balance
- High ESD level
- Low VSWR
- Die Package

Model No. Description

FACXXXX

XX- attenuation: **dB.

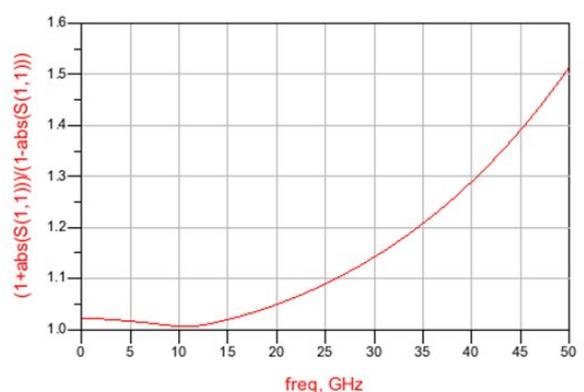
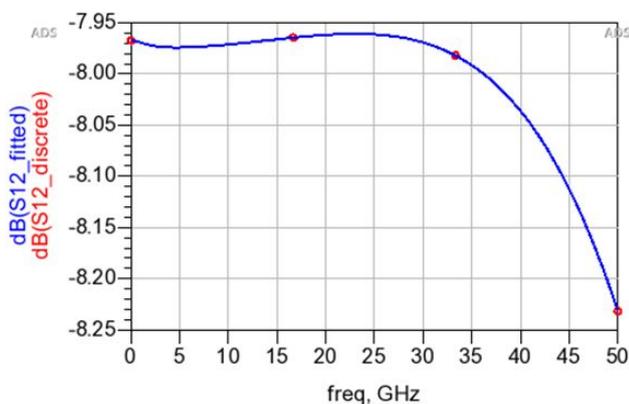
XX-frequency range 06: DC to 6GHz
 10: DC to 10GHz
 12: DC to 12.4GHz
 18: DC to 18GHz
 26: DC to 26.5GHz.
 43: DC to 43.5GHz.

Specifications

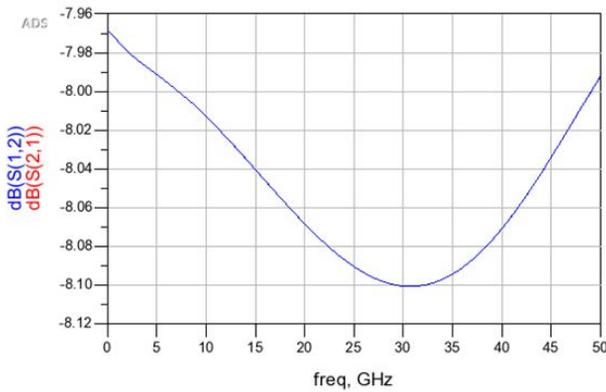
Frequency Range	DC to 43.5GHz
Attenuation	8 dB
Nonimal Impeance	50 Ohm
Rated Input Power	1.2W@25℃ 1W@85℃
Operating Temperature	-45 ℃ to +85 ℃

Paramter	The testing result of bare chip in probe station		Test result of add 300um double wire-bonding	
	Freq.Range (GHz)	Typ.	Freq.Range (GHz)	Typ.
Attenuation (dB)	DC-5	8±0.10	DC-5	8±0.10
	5-15	8±0.10	5-15	8±0.10
	15-18	8±0.15	15-18	8±0.15
	18-26.5	8±0.25	18-26.5	8±0.25
	26.5-43.5	8±0.25	26.5-43.5	8±0.25
VSWR (:1)	DC-5	1.10	DC-5	1.15
	5-15	1.10	5-15	1.20
	15-18	1.10	15-18	1.25
	18-26.5	1.25	18-26.5	1.35
	26.5-43.5	1.40	26.5-43.5	1.35

Test Curve

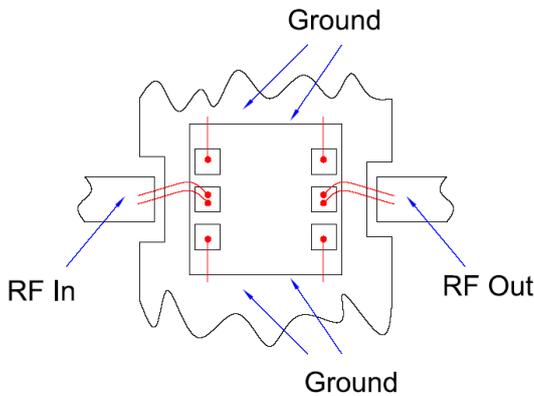


The testing result of bare chip in probe station



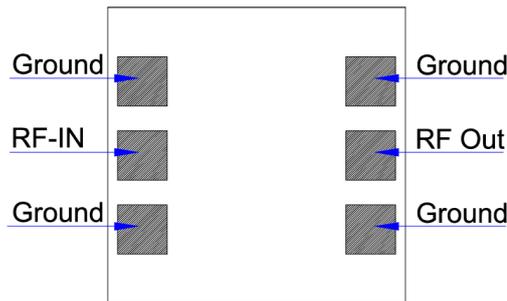
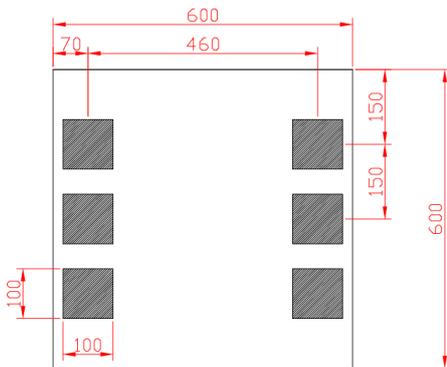
Test result of add 300um double wire-bonding

Recommended Layout



Package Outlines

Note: all dimensions shown in um



Parameter	value (um)
Thickness	100
width	600
length	600
Electrode size	100x100